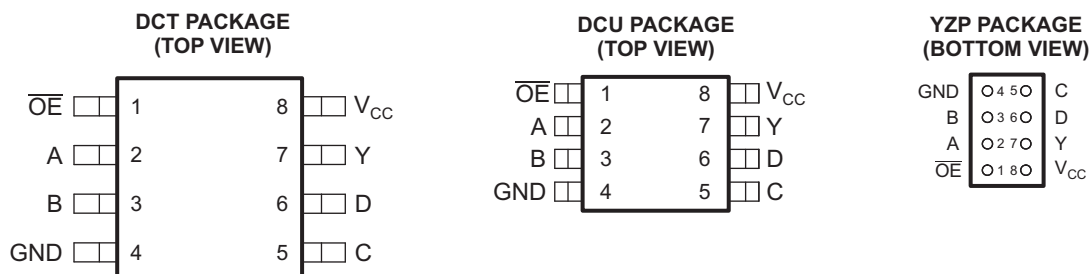


ULTRA-CONFIGURABLE MULTIPLE-FUNCTION GATE WITH 3-STATE OUTPUT

Check for Samples: [SN74LVC1G99](#)

FEATURES

- Available in Texas Instruments NanoFree™ Package
- Supports 5-V V_{CC} Operation
- Inputs Accept Voltages to 5.5 V
- Max t_{pd} of 6.7 ns at 3.3 V
- Low Power Consumption, 10- μ A Max I_{CC}
- ± 24 -mA Output Drive at 3.3 V
- Offers Nine Different Logic Functions in a Single Package
- I_{off} Supports Partial-Power-Down Mode Operation
- Input Hysteresis Allows for Slow Input Transition Time and Better Noise Immunity at Input
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)



See mechanical drawings for dimensions.

DESCRIPTION/ORDERING INFORMATION

The SN74LVC1G99 is operational from 1.65 V to 5.5 V.

The SN74LVC1G99 features configurable multiple functions with a 3-state output. The output is disabled when the output-enable (\overline{OE}) input is high. When \overline{OE} is low, the output state is determined by 16 patterns of 4-bit input. The user can choose logic functions, such as MUX, AND, OR, NAND, NOR, XOR, XNOR, inverter, and buffer. All inputs can be connected to V_{CC} or GND.

This device functions as an independent inverter, but because of Schmitt action, it has different input threshold levels for positive-going (V_{T+}) and negative-going (V_{T-}) signals.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Table 1. ORDERING INFORMATION

| T_A | PACKAGE ⁽¹⁾ ⁽²⁾ | | ORDERABLE PART NUMBER | TOP-SIDE MARKING ⁽³⁾ |
|---------------|--|-----------------|-----------------------|---------------------------------|
| –40°C to 85°C | NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free) | Reel of 3000 | SN74LVC1G99YZPR | DE_ |
| | | Reel of 3000 | SN74LVC1G99DCTR | C99_ _ _ |
| | Reel of 250 | SN74LVC1G99DCTT | | |
| | VSSOP – DCU | Reel of 3000 | SN74LVC1G99DCUR | C99_ |
| | | Reel of 250 | SN74LVC1G99DCUT | |

(1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

(2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

(3) DCT: The actual top-side marking has three additional characters that designate the year, month, and assembly/test site.

DCU: The actual top-side marking has one additional character that designates the assembly/test site.

YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).

DESCRIPTION/ORDERING INFORMATION (CONTINUED)

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

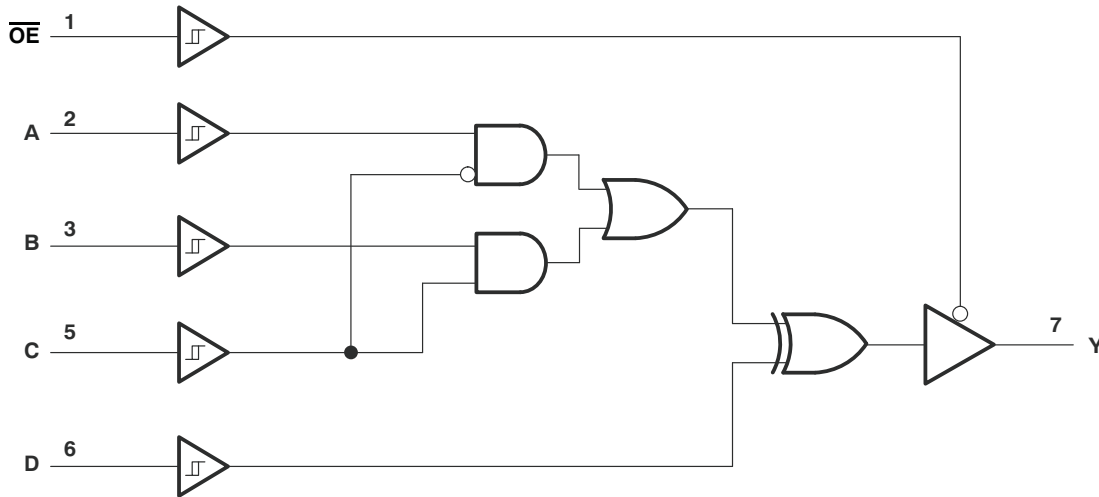
This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

NanoFree™ package technologies are a major breakthrough in IC packaging concepts, using the die as the package.

FUNCTION TABLE

| INPUTS | | | | | OUTPUT |
|-----------------|--------|--------|--------|--------|--------|
| \overline{OE} | D | C | B | A | Y |
| L | L | L | L | L | L |
| L | L | L | L | H | H |
| L | L | L | H | L | L |
| L | L | L | H | H | H |
| L | L | H | L | L | L |
| L | L | H | L | H | L |
| L | L | H | H | L | H |
| L | L | H | H | H | H |
| L | H | L | L | L | H |
| L | H | L | L | H | L |
| L | H | L | H | L | H |
| L | H | L | H | H | L |
| L | H | H | L | L | H |
| L | H | H | L | H | H |
| L | H | H | H | L | L |
| L | H | H | H | H | L |
| H | H or L | H or L | H or L | H or L | Z |

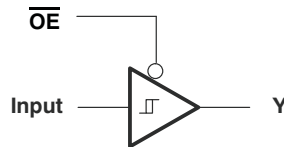
LOGIC DIAGRAM (POSITIVE LOGIC)



FUNCTION SELECTION TABLE

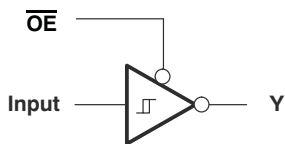
| PRIMARY FUNCTION | COMPLEMENTARY FUNCTION | PAGE |
|--|---|------|
| 3-state buffer | | 3 |
| 3-state inverter | | 3 |
| 3-state 2-in-1 data selector MUX | | 4 |
| 3-state 2-in-1 data selector MUX, inverted out | | 4 |
| 3-state 2-input AND | 3-state 2-input NOR, both inputs inverted | 5 |
| 3-state 2-input AND, one input inverted | 3-state 2-input NOR, one input inverted | 5 |
| 3-state 2-input AND, both inputs inverted | 3-state 2-input NOR | 5 |
| 3-state 2-input NAND | 3-state 2-input OR, both inputs inverted | 6 |
| 3-state 2-input NAND, one input inverted | 3-state 2-input OR, one input inverted | 6 |
| 3-state 2-input NAND, both inputs inverted | 3-state 2-input OR | 6 |
| 3-state 2-input XOR | | 7 |
| 3-state 2-input XNOR | 3-state 2-input XOR, one input inverted | 7 |

3-STATE BUFFER FUNCTIONS AVAILABLE



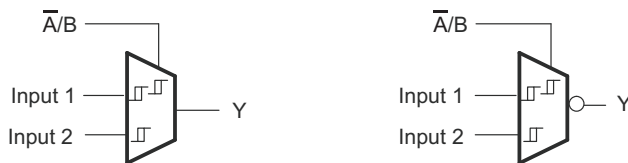
| FUNCTION | \overline{OE} | A | B | C | D |
|----------------|-----------------|--------|--------|--------|-------|
| 3-state buffer | L | Input | H or L | L | L |
| | | H or L | Input | H | L |
| | | L | H | Input | L |
| | | H | L | Input | H |
| | | H | H or L | L | Input |
| | | H or L | L | H | Input |
| | | L | L | H or L | Input |

3-STATE INVERTER FUNCTIONS AVAILABLE



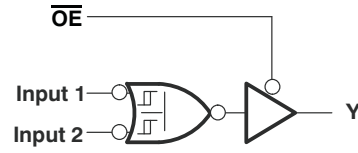
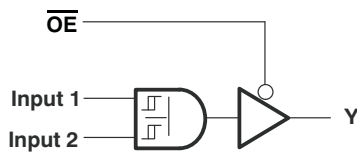
| FUNCTION | \overline{OE} | A | B | C | D |
|----------------|-----------------|--------|--------|--------|-------|
| 3-state buffer | L | Input | H or L | L | H |
| | | X | Input | H | H |
| | | L | H | Input | H |
| | | H | L | Input | L |
| | | H | H or L | L | Input |
| | | H or L | H | H | Input |
| | | H | H | H or L | Input |

3-STATE MUX FUNCTIONS AVAILABLE

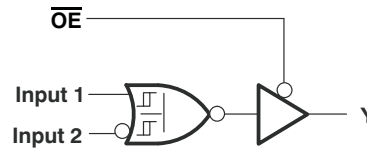
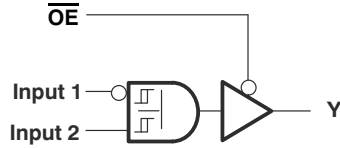


| FUNCTION | \overline{OE} | A | B | C | D |
|---|-----------------|---------|---------|--|---|
| 3-state 2-to-1, data selector MUX | L | Input 1 | Input 2 | $\overline{\text{Input 1}}$ or Input 2 | L |
| 3-state 2-to-1, data selector MUX | | Input 2 | Input 1 | $\overline{\text{Input 2}}$ or Input 1 | L |
| 3-state 2-to-1, data selector MUX, inverted out | | Input 1 | Input 2 | $\overline{\text{Input 1}}$ or Input 2 | H |
| 3-state 2-to-1, data selector MUX, inverted out | | Input 2 | Input 1 | $\overline{\text{Input 2}}$ or Input 1 | H |

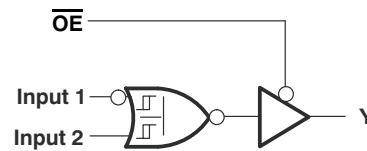
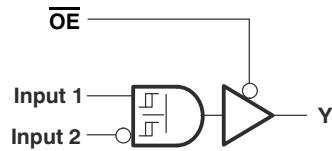
3-STATE AND/NOR/OR FUNCTIONS AVAILABLE



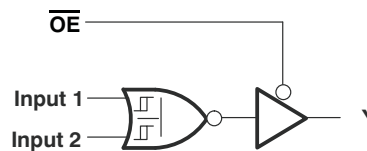
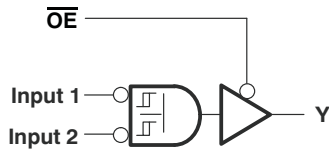
| NO. OF INPUTS | AND/NAND FUNCTION | OR/NOR FUNCTION | \overline{OE} | A | B | C | D |
|---------------|-------------------|-----------------|-----------------|---|---------|---------|---|
| 2 | 3-state AND | 3-state NOR | L | L | Input 1 | Input 2 | L |
| 2 | 3-state AND | 3-state NOR | | L | Input 2 | Input 1 | L |



| NO. OF INPUTS | AND/NAND FUNCTION | OR/NOR FUNCTION | \overline{OE} | A | B | C | D |
|---------------|-------------------|-----------------|-----------------|---------|---------|---------|---|
| 2 | 3-state AND | 3-state NOR | L | Input 2 | L | Input 1 | L |
| 2 | 3-state AND | 3-state NOR | | H | Input 1 | Input 2 | H |

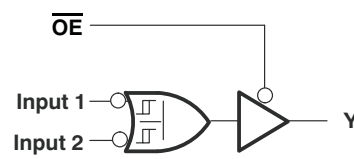
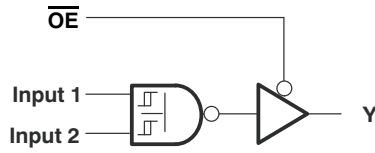


| NO. OF INPUTS | AND/NAND FUNCTION | OR/NOR FUNCTION | \overline{OE} | A | B | C | D |
|---------------|-------------------|-----------------|-----------------|---------|---------|---------|---|
| 2 | 3-state AND | 3-state NOR | L | Input 1 | L | Input 2 | L |
| 2 | 3-state AND | 3-state NOR | | H | Input 2 | Input 1 | H |

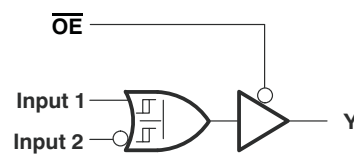
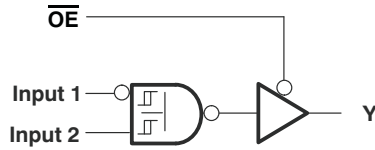


| NO. OF INPUTS | AND/NAND FUNCTION | OR/NOR FUNCTION | \overline{OE} | A | B | C | D |
|---------------|-----------------------------------|-----------------|-----------------|---------|---|---------|---|
| 2 | 3-state AND, both inverted inputs | 3-state NOR | L | Input 1 | H | Input 2 | H |
| 2 | 3-state AND, both inverted inputs | 3-state NOR | | Input 2 | H | Input 1 | H |

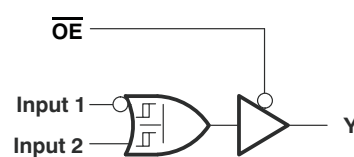
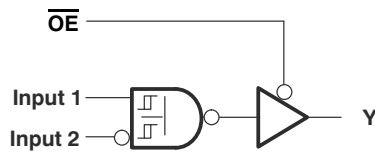
3-STATE NAND/OR FUNCTIONS AVAILABLE



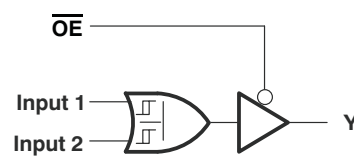
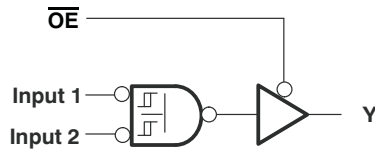
| NO. OF INPUTS | AND/NAND FUNCTION | OR/NOR FUNCTION | \overline{OE} | A | B | C | D |
|---------------|-------------------|-----------------|-----------------|---|---------|---------|---|
| 2 | 3-state NAND | 3-state OR | L | L | Input 1 | Input 2 | H |
| 2 | 3-state NAND | 3-state OR | | L | Input 2 | Input 1 | H |



| NO. OF INPUTS | AND/NAND FUNCTION | OR/NOR FUNCTION | \overline{OE} | A | B | C | D |
|---------------|-------------------|-----------------|-----------------|---------|---------|---------|---|
| 2 | 3-state NAND | 3-state OR | L | Input 2 | L | Input 1 | H |
| 2 | 3-state NAND | 3-state OR | | H | Input 1 | Input 2 | L |

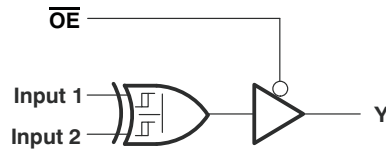


| NO. OF INPUTS | AND/NAND FUNCTION | OR/NOR FUNCTION | \overline{OE} | A | B | C | D |
|---------------|-------------------|-----------------|-----------------|---------|---------|---------|---|
| 2 | 3-state NAND | 3-state OR | L | Input 1 | L | Input 2 | H |
| 2 | 3-state NAND | 3-state OR | | H | Input 2 | Input 1 | L |

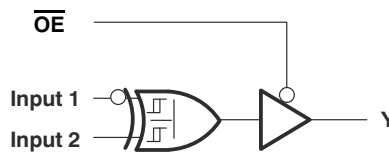


| NO. OF INPUTS | AND/NAND FUNCTION | OR/NOR FUNCTION | \overline{OE} | A | B | C | D |
|---------------|-------------------|-----------------|-----------------|---------|---|---------|---|
| 2 | 3-state NAND | 3-state OR | L | Input 1 | H | Input 2 | L |
| 2 | 3-state NAND | 3-state OR | | Input 2 | H | Input 1 | L |

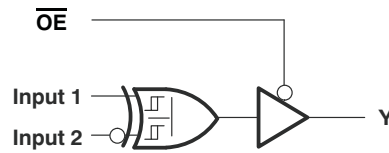
3-STATE XOR/XNOR FUNCTIONS AVAILABLE



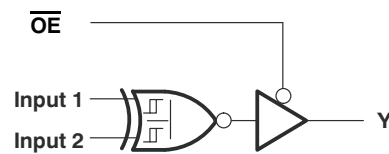
| FUNCTION | \overline{OE} | A | B | C | D |
|-------------|-----------------|---------|---------|---------|---------|
| 3-state XOR | L | Input 1 | H or L | L | Input 2 |
| | | Input 2 | H or L | L | Input 1 |
| | | H or L | Input 1 | H | Input 2 |
| | | H or L | Input 2 | H | Input 1 |
| | | L | H | Input 1 | Input 2 |
| | | L | H | Input 2 | Input 1 |



| FUNCTION | \overline{OE} | A | B | C | D |
|-------------|-----------------|---|---|---------|---------|
| 3-state XOR | L | H | L | Input 1 | Input 2 |



| FUNCTION | \overline{OE} | A | B | C | D |
|-------------|-----------------|---|---|---------|---------|
| 3-state XOR | L | H | L | Input 1 | Input 2 |



| FUNCTION | \overline{OE} | A | B | C | D |
|--------------|-----------------|---|---|---------|---------|
| 3-state XNOR | L | H | L | Input 1 | Input 2 |
| 3-state XNOR | | H | L | Input 2 | Input 1 |

Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

| | | MIN | MAX | UNIT |
|------------------|---|--------------------|-----------------------|------|
| V _{CC} | Supply voltage range | -0.5 | 6.5 | V |
| V _I | Input voltage range ⁽²⁾ | -0.5 | 6.5 | V |
| V _O | Voltage range applied to any output in the high-impedance or power-off state ⁽²⁾ | -0.5 | 6.5 | V |
| V _O | Voltage range applied to any output in the high or low state ^{(2) (3)} | -0.5 | V _{CC} + 0.5 | V |
| I _{IK} | Input clamp current | V _I < 0 | -50 | mA |
| I _{OK} | Output clamp current | V _O < 0 | -50 | mA |
| I _O | Continuous output current | | ±50 | mA |
| | Continuous current through V _{CC} or GND | | ±100 | mA |
| θ _{JA} | Package thermal impedance ⁽⁴⁾ | DCT package | 220 | °C/W |
| | | DCU package | 227 | |
| | | YZP package | 102 | |
| T _{stg} | Storage temperature range | -65 | 150 | °C |

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output negative voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) The value of V_{CC} is provided in the recommended operating conditions table.
- (4) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions⁽¹⁾

| | | MIN | MAX | UNIT | |
|-----------------|------------------------------------|---|-----------------|------|------|
| V _{CC} | Supply voltage | Operating | 1.65 | 5.5 | V |
| | | Data retention only | 1.5 | | |
| V _I | Input voltage | 0 | 5.5 | V | |
| V _O | Output voltage | 0 | V _{CC} | V | |
| I _{OH} | High-level output current | V _{CC} = 1.65 V | | -4 | mA |
| | | V _{CC} = 2.3 V | | -8 | |
| | | V _{CC} = 3 V | | -16 | |
| | | V _{CC} = 4.5 V | | -24 | |
| I _{OL} | Low-level output current | V _{CC} = 1.65 V | | 4 | mA |
| | | V _{CC} = 2.3 V | | 8 | |
| | | V _{CC} = 3 V | | 16 | |
| | | V _{CC} = 4.5 V | | 24 | |
| Δt/Δv | Input transition rise or fall rate | V _{CC} = 1.8 V ± 0.15 V, 2.5 V ± 0.2 V | | 20 | ns/V |
| | | V _{CC} = 3.3 V ± 0.3 V | | 10 | |
| | | V _{CC} = 5 V ± 0.5 V | | 5 | |

- (1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number [SCBA004](#).

Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | V _{CC} | MIN | TYP ⁽¹⁾ | MAX | UNIT |
|---|---|--------------------|-----------------------|--------------------|------|------|
| V _{T+} Positive-going input threshold voltage | | 1.65 V | 0.79 | | 1.26 | V |
| | | 2.3 V | 1.11 | | 1.66 | |
| | | 3 V | 1.5 | | 1.97 | |
| | | 4.5 V | 2.16 | | 2.84 | |
| | | 5.5 V | 2.61 | | 3.43 | |
| V _{T-} Negative- going input threshold voltage | | 1.65 V | 0.39 | | 0.72 | V |
| | | 2.3 V | 0.58 | | 0.97 | |
| | | 3 V | 0.84 | | 1.24 | |
| | | 4.5 V | 1.41 | | 1.89 | |
| | | 5.5 V | 1.87 | | 2.39 | |
| ΔV _T Hysteresis (V _{T+} – V _{T-}) | | 1.65 V | 0.37 | | 0.72 | V |
| | | 2.3 V | 0.48 | | 0.87 | |
| | | 3 V | 0.56 | | 0.97 | |
| | | 4.5 V | 0.71 | | 1.14 | |
| | | 5.5 V | 0.71 | | 1.21 | |
| V _{OH} | I _{OH} = –100 μA | 1.65 V to 5.5 V | V _{CC} – 0.1 | | | V |
| | I _{OH} = –4 mA | 1.65 V | 1.2 | | | |
| | I _{OH} = –8 mA | 2.3 V | 1.9 | | | |
| | I _{OH} = –16 mA | 3 V | 2.4 | | | |
| | I _{OH} = –24 mA | | 2.3 | | | |
| | I _{OH} = –32 mA | 4.5 V | 3.8 | | | |
| V _{OL} | I _{OL} = 100 μA | 1.65 V to 5.5 V | | | 0.1 | V |
| | I _{OL} = 4 mA | 1.65 V | | | 0.45 | |
| | I _{OL} = 8 mA | 2.3 V | | | 0.3 | |
| | I _{OL} = 16 mA | 3 V | | | 0.4 | |
| | I _{OL} = 24 mA | | | | 0.55 | |
| | I _{OL} = 32 mA | 4.5 V | | | 0.55 | |
| I _I | V _I = 5.5 V or GND | 0 V to 5.5 V | | | ±5 | μA |
| I _{off} | V _I or V _O = 5.5 V | 0 V | | | ±10 | μA |
| I _{OZ} | V _O = V _{CC} or GND | 1.65 V to 5.5 V | | | ±10 | μA |
| I _{CC} | V _I = 5.5 V or GND, I _O = 0 | 1.65 V to 5.5 V | | | 10 | μA |
| ΔI _{CC} | One input at V _{CC} – 0.6 V, Other inputs at V _{CC} or GND | 3 V to 5.5 V | | | 500 | μA |
| C _i | V _I = V _{CC} or GND | 3.3 V | | | 3.5 | pF |
| C _o | V _O = V _{CC} or GND | 3.3 V | | | 6 | pF |

(1) T_A = 25°C

Switching Characteristics

 over recommended operating free-air temperature range, $C_L = 15$ pF (unless otherwise noted) (see [Figure 1](#))

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $V_{CC} = 1.8\text{ V} \pm 0.15\text{ V}$ | | $V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$ | | $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$ | | $V_{CC} = 5\text{ V} \pm 0.5\text{ V}$ | | UNIT |
|-----------|-----------------|----------------|---|------|--|------|--|-----|--|-----|------|
| | | | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | |
| t_{pd} | A | Y | 4.5 | 30.1 | 2.5 | 11.3 | 1.8 | 7.5 | 1.3 | 4.8 | ns |
| | B | | 4.4 | 28.3 | 2.4 | 10.8 | 1.8 | 7.2 | 1.3 | 4.7 | |
| | C | | 4.4 | 29.1 | 2.4 | 11.7 | 1.9 | 7.6 | 1.3 | 5 | |
| | D | | 4.3 | 25.1 | 2.4 | 10.2 | 1.7 | 6.7 | 1.3 | 4.5 | |
| t_{en} | \overline{OE} | Y | 3.4 | 24.7 | 2.1 | 10 | 1.3 | 5.8 | 1 | 3.8 | ns |
| t_{dis} | \overline{OE} | Y | 4 | 15.5 | 2.7 | 7.5 | 3.5 | 7 | 2 | 5.5 | ns |

Switching Characteristics

 over recommended operating free-air temperature range, $C_L = 30$ pF or 50 pF (unless otherwise noted) (see [Figure 2](#))

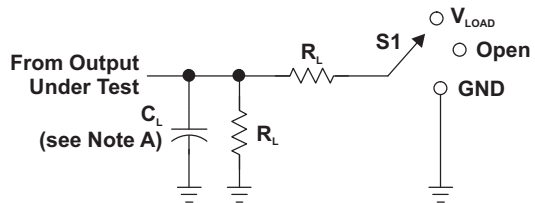
| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $V_{CC} = 1.8\text{ V} \pm 0.15\text{ V}$ | | $V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$ | | $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$ | | $V_{CC} = 5\text{ V} \pm 0.5\text{ V}$ | | UNIT |
|-----------|-----------------|----------------|---|------|--|------|--|-----|--|-----|------|
| | | | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | |
| t_{pd} | A | Y | 4.6 | 30.8 | 2.6 | 11.7 | 2.4 | 8.4 | 1.8 | 5.5 | ns |
| | B | | 4.6 | 28.9 | 2.6 | 11.3 | 2.3 | 8.2 | 1.8 | 5.4 | |
| | C | | 4.4 | 29.8 | 2.5 | 12.3 | 2.5 | 8.6 | 1.8 | 5.7 | |
| | D | | 4.3 | 25.7 | 2.5 | 10.7 | 2.4 | 7.6 | 1.6 | 5.2 | |
| t_{en} | \overline{OE} | Y | 4.2 | 25.2 | 2.4 | 11.3 | 2 | 7 | 1.7 | 4.7 | ns |
| t_{dis} | \overline{OE} | Y | 3.7 | 15 | 2 | 5.8 | 2.1 | 5.6 | 1 | 4.5 | ns |

Operating Characteristics

 $T_A = 25^\circ\text{C}$

| PARAMETER | TEST CONDITIONS | $V_{CC} = 1.8\text{ V}$ | $V_{CC} = 2.5\text{ V}$ | $V_{CC} = 3.3\text{ V}$ | $V_{CC} = 5\text{ V}$ | UNIT |
|--|---------------------|-------------------------|-------------------------|-------------------------|-----------------------|------|
| | | TYP | TYP | TYP | TYP | |
| C_{pd} Power dissipation capacitance | $f = 10\text{ MHz}$ | 19 | 20 | 22 | 27 | pF |

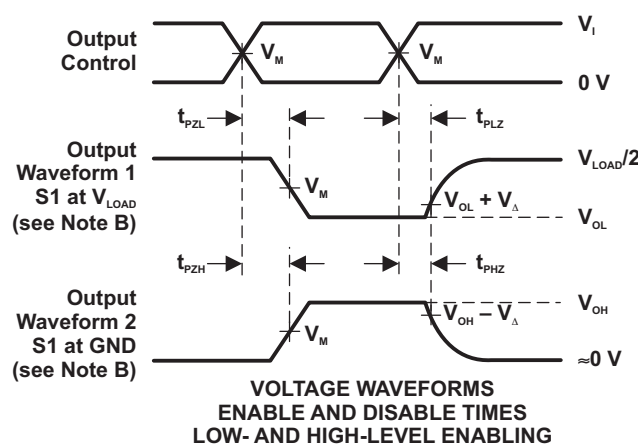
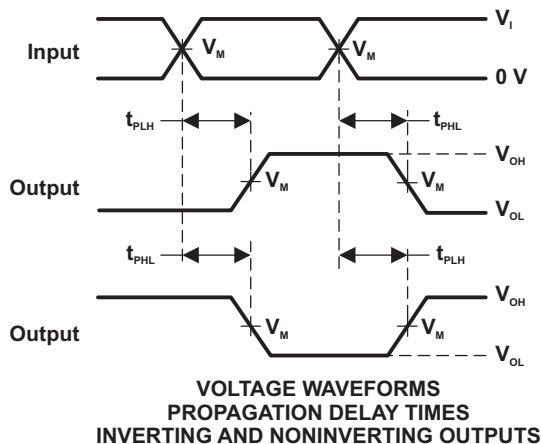
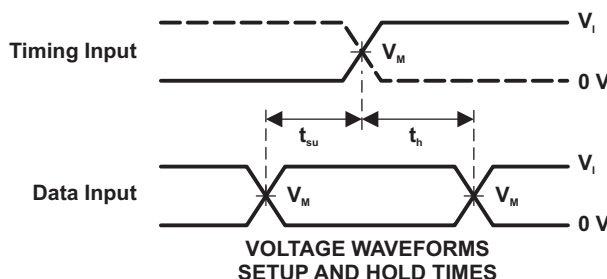
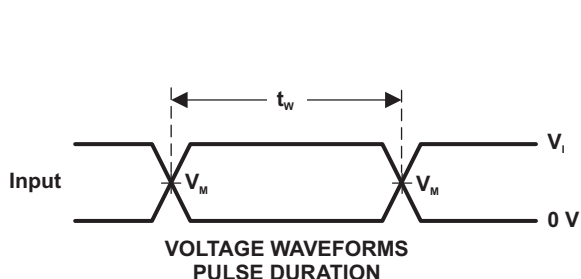
PARAMETER MEASUREMENT INFORMATION



LOAD CIRCUIT

| TEST | S1 |
|-------------------|------------|
| t_{PLH}/t_{PHL} | Open |
| t_{PLZ}/t_{PZL} | V_{LOAD} |
| t_{PHZ}/t_{PZH} | GND |

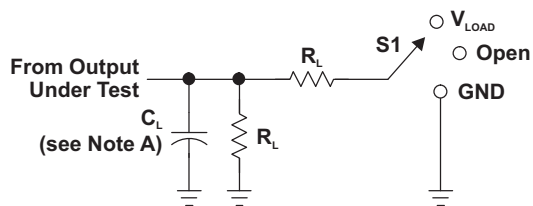
| V_{CC} | INPUTS | | V_M | V_{LOAD} | C_L | R_L | V_{Δ} |
|----------------------------------|----------|----------------------|------------|-------------------|-------|--------------|--------------|
| | V_I | t_r/t_f | | | | | |
| $1.8\text{ V} \pm 0.15\text{ V}$ | V_{CC} | $\leq 2\text{ ns}$ | $V_{CC}/2$ | $2 \times V_{CC}$ | 15 pF | 1 M Ω | 0.15 V |
| $2.5\text{ V} \pm 0.2\text{ V}$ | V_{CC} | $\leq 2\text{ ns}$ | $V_{CC}/2$ | $2 \times V_{CC}$ | 15 pF | 1 M Ω | 0.15 V |
| $3.3\text{ V} \pm 0.3\text{ V}$ | 3 V | $\leq 2.5\text{ ns}$ | 1.5 V | 6 V | 15 pF | 1 M Ω | 0.3 V |
| $5\text{ V} \pm 0.5\text{ V}$ | V_{CC} | $\leq 2.5\text{ ns}$ | $V_{CC}/2$ | $2 \times V_{CC}$ | 15 pF | 1 M Ω | 0.3 V |



- NOTES: A. C_L includes probe and jig capacitance.
 B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_o = 50\ \Omega$.
 D. The outputs are measured one at a time, with one transition per measurement.
 E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 F. t_{PZL} and t_{PZH} are the same as t_{en} .
 G. t_{PLH} and t_{PHL} are the same as t_{pd} .
 H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

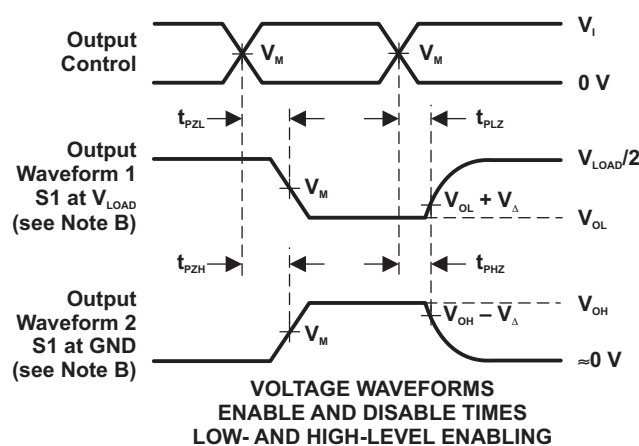
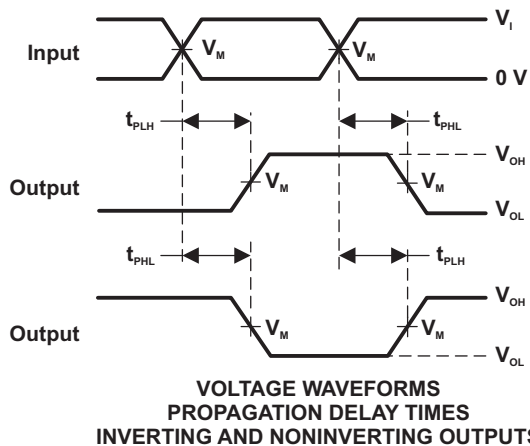
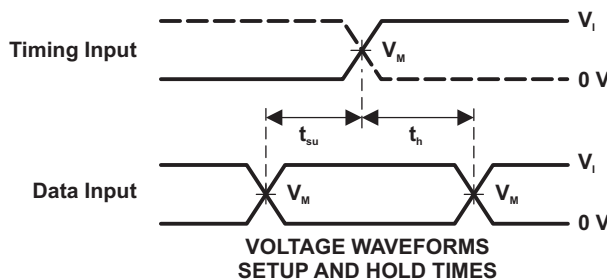
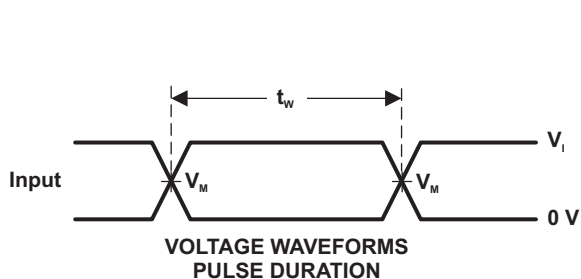
PARAMETER MEASUREMENT INFORMATION (continued)



LOAD CIRCUIT

| TEST | S1 |
|-------------------|------------|
| t_{PLH}/t_{PHL} | Open |
| t_{PLZ}/t_{PZL} | V_{LOAD} |
| t_{PHZ}/t_{PZH} | GND |

| V_{CC} | INPUTS | | V_M | V_{LOAD} | C_L | R_L | V_{Δ} |
|----------------------------------|----------|----------------------|------------|-------------------|-------|--------------|--------------|
| | V_I | t_f/t_r | | | | | |
| $1.8\text{ V} \pm 0.15\text{ V}$ | V_{CC} | $\leq 2\text{ ns}$ | $V_{CC}/2$ | $2 \times V_{CC}$ | 30 pF | 1 k Ω | 0.15 V |
| $2.5\text{ V} \pm 0.2\text{ V}$ | V_{CC} | $\leq 2\text{ ns}$ | $V_{CC}/2$ | $2 \times V_{CC}$ | 30 pF | 500 Ω | 0.15 V |
| $3.3\text{ V} \pm 0.3\text{ V}$ | 3 V | $\leq 2.5\text{ ns}$ | 1.5 V | 6 V | 50 pF | 500 Ω | 0.3 V |
| $5\text{ V} \pm 0.5\text{ V}$ | V_{CC} | $\leq 2.5\text{ ns}$ | $V_{CC}/2$ | $2 \times V_{CC}$ | 50 pF | 500 Ω | 0.3 V |



- NOTES: A. C_L includes probe and jig capacitance.
 B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_o = 50\ \Omega$.
 D. The outputs are measured one at a time, with one transition per measurement.
 E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 F. t_{PZL} and t_{PZH} are the same as t_{on} .
 G. t_{PLH} and t_{PHL} are the same as t_{pd} .
 H. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms

REVISION HISTORY

| Changes from Revision E (October 2007) to Revision F | Page |
|--|------|
| • Changed document template from TIMS format to DocZone format. | 1 |
| • Changed 3-State Mux graphic to fix labeling error. | 5 |

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead/Ball Finish | MSL Peak Temp (3) | Op Temp (°C) | Top-Side Markings (4) | Samples |
|-------------------|---------------|--------------|-----------------|------|-------------|-------------------------|------------------|----------------------|--------------|--------------------------|-------------------------|
| SN74LVC1G99DCTR | ACTIVE | SM8 | DCT | 8 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | C99 Z | Samples |
| SN74LVC1G99DCTRE4 | ACTIVE | SM8 | DCT | 8 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | C99 Z | Samples |
| SN74LVC1G99DCTRG4 | ACTIVE | SM8 | DCT | 8 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | C99 Z | Samples |
| SN74LVC1G99DCTT | ACTIVE | SM8 | DCT | 8 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | C99 Z | Samples |
| SN74LVC1G99DCTTE4 | ACTIVE | SM8 | DCT | 8 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | C99 Z | Samples |
| SN74LVC1G99DCTTG4 | ACTIVE | SM8 | DCT | 8 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | C99 Z | Samples |
| SN74LVC1G99DCUR | ACTIVE | US8 | DCU | 8 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | C99R | Samples |
| SN74LVC1G99DCURE4 | ACTIVE | US8 | DCU | 8 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | C99R | Samples |
| SN74LVC1G99DCUT | ACTIVE | US8 | DCU | 8 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | C99R | Samples |
| SN74LVC1G99DCUTE4 | ACTIVE | US8 | DCU | 8 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | C99R | Samples |
| SN74LVC1G99DCUTG4 | ACTIVE | US8 | DCU | 8 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | C99R | Samples |
| SN74LVC1G99YEPR | OBSOLETE | DSBGA | YEP | 8 | | TBD | Call TI | Call TI | -40 to 85 | | |
| SN74LVC1G99YZPR | ACTIVE | DSBGA | YZP | 8 | 3000 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM | -40 to 85 | (DE2 ~ DE7) | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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OTHER QUALIFIED VERSIONS OF SN74LVC1G99 :

- Automotive: [SN74LVC1G99-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION
REEL DIMENSIONS

TAPE DIMENSIONS


| | |
|----|---|
| A0 | Dimension designed to accommodate the component width |
| B0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

TAPE AND REEL INFORMATION

*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-----------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| SN74LVC1G99DCUR | US8 | DCU | 8 | 3000 | 180.0 | 8.4 | 2.25 | 3.35 | 1.05 | 4.0 | 8.0 | Q3 |
| SN74LVC1G99YZPR | DSBGA | YZP | 8 | 3000 | 180.0 | 8.4 | 1.02 | 2.02 | 0.63 | 4.0 | 8.0 | Q1 |

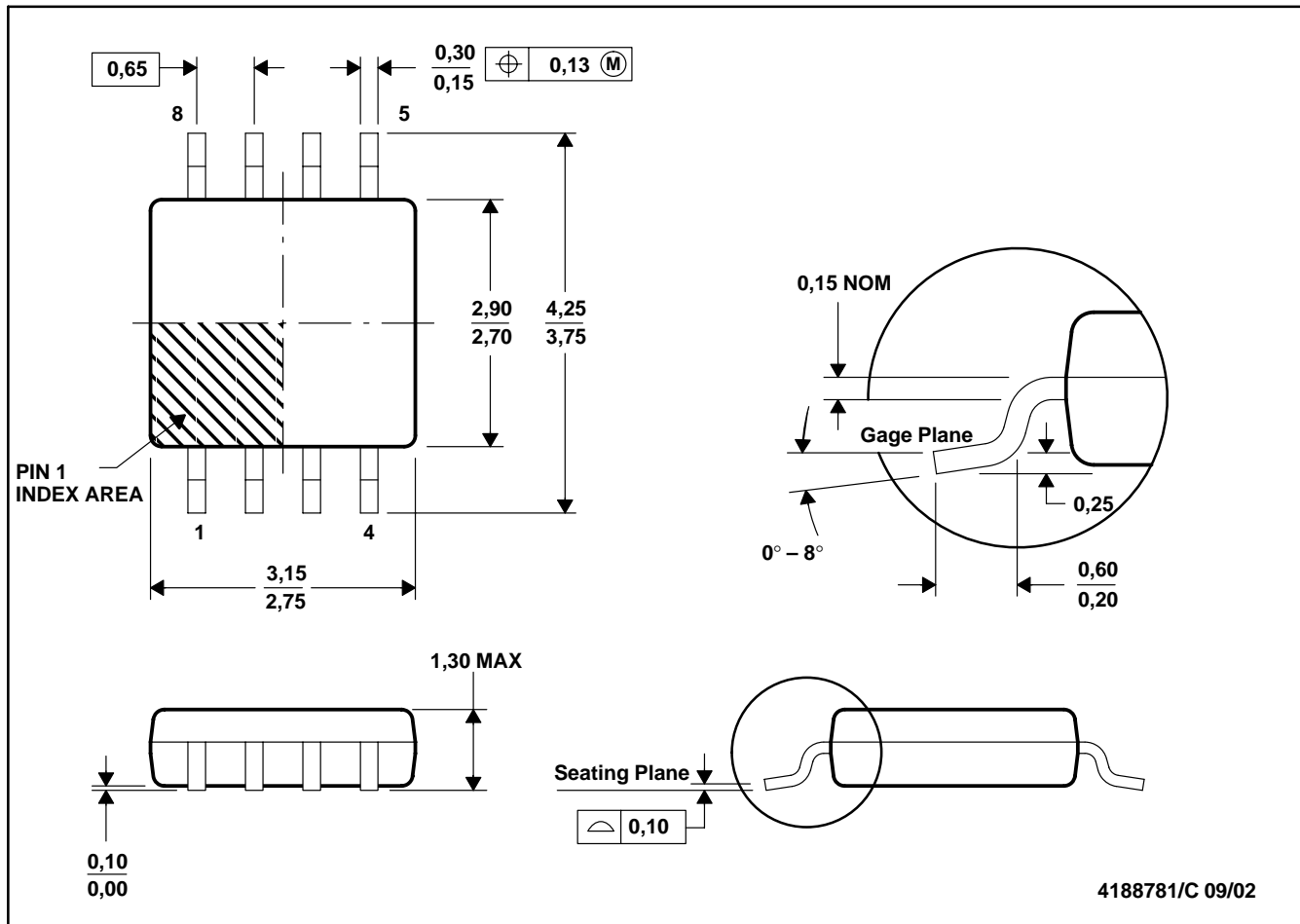
TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| SN74LVC1G99DCUR | US8 | DCU | 8 | 3000 | 202.0 | 201.0 | 28.0 |
| SN74LVC1G99YZPR | DSBGA | YZP | 8 | 3000 | 220.0 | 220.0 | 34.0 |

DCT (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion
D. Falls within JEDEC MO-187 variation DA.

DCT (R-PDSO-G8)

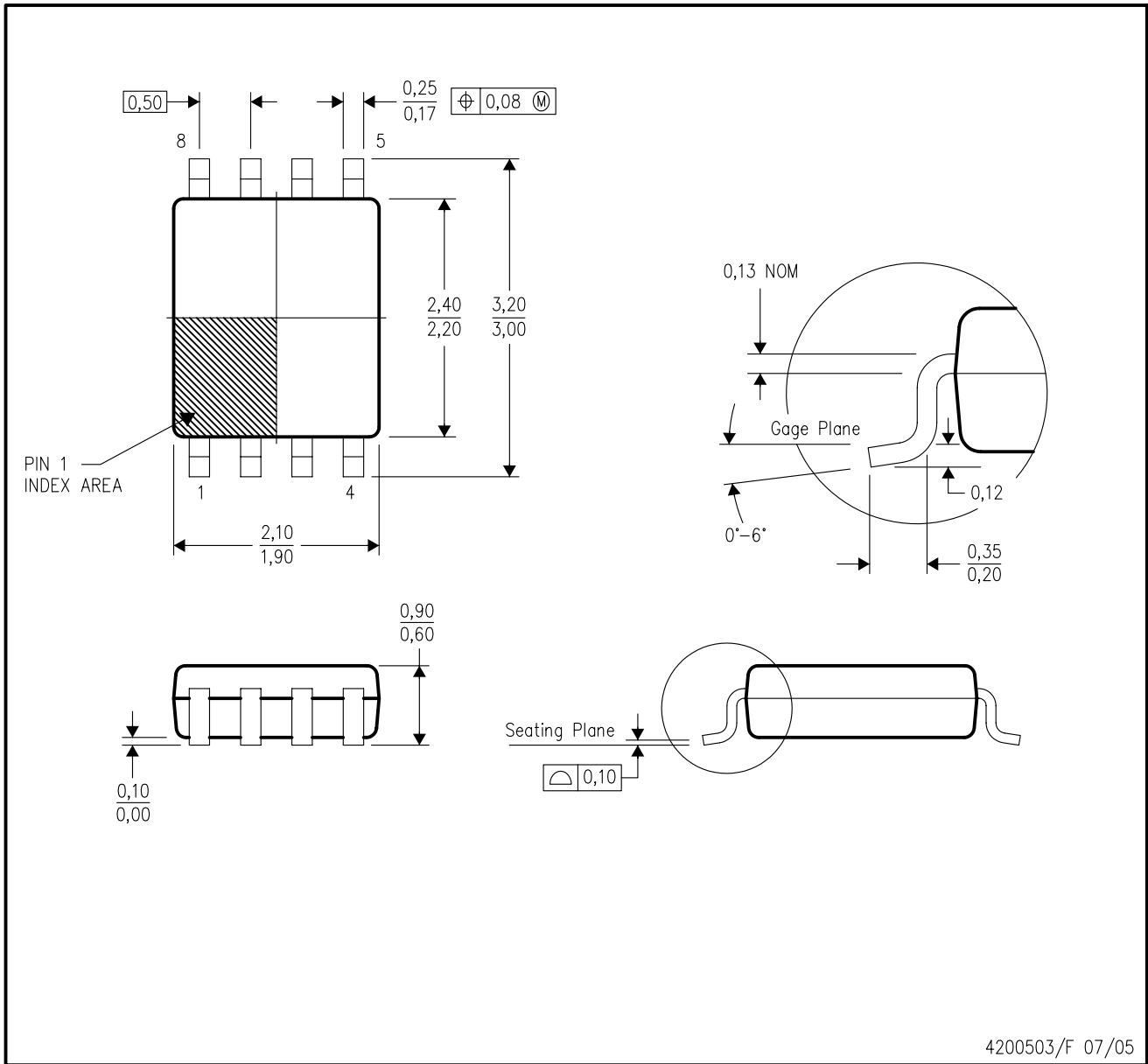
PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
 - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

DCU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



4200503/F 07/05

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-187 variation CA.

DCU (S-PDSO-G8)

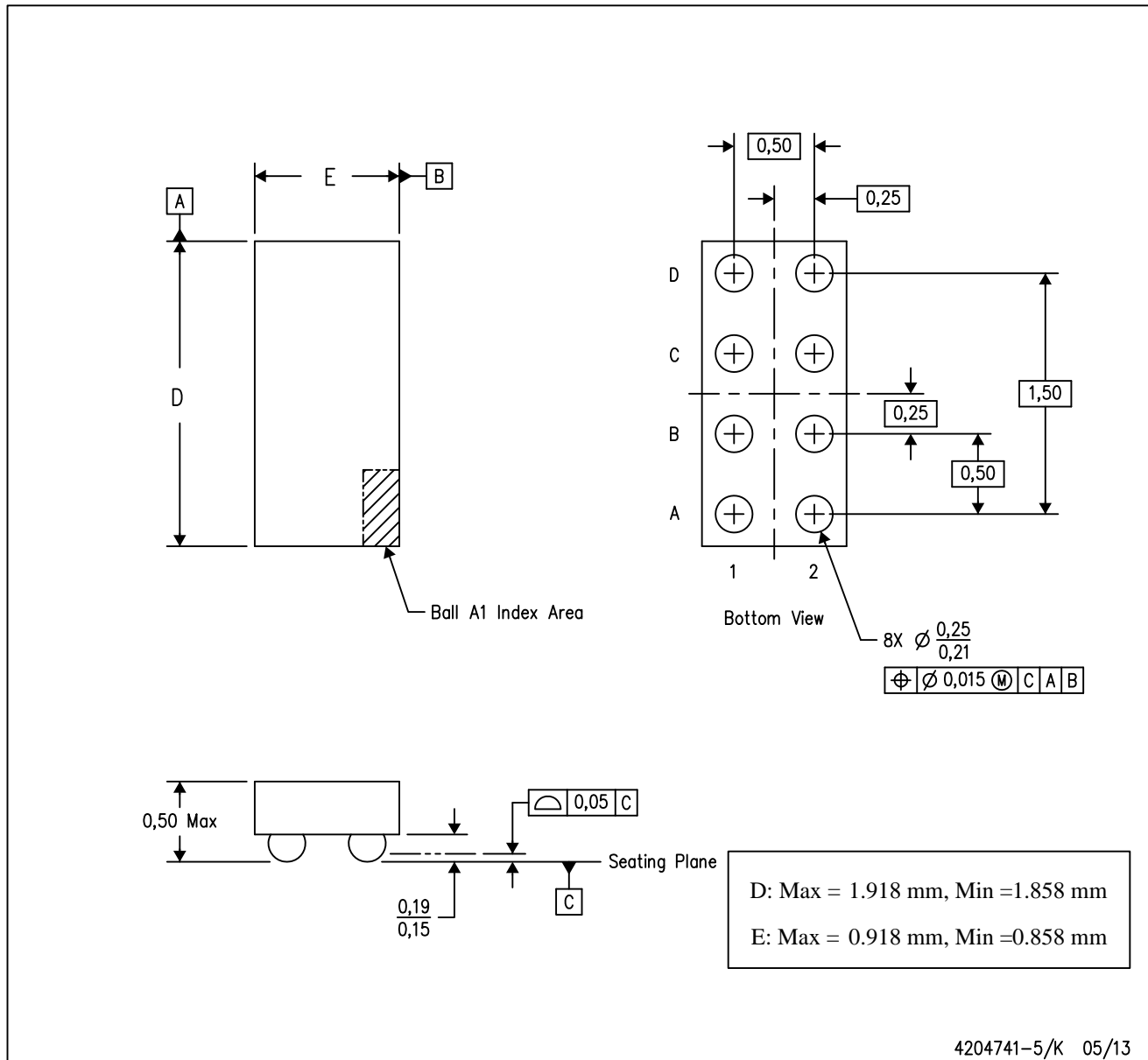
PLASTIC SMALL OUTLINE PACKAGE (DIE DOWN)



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

YZP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY

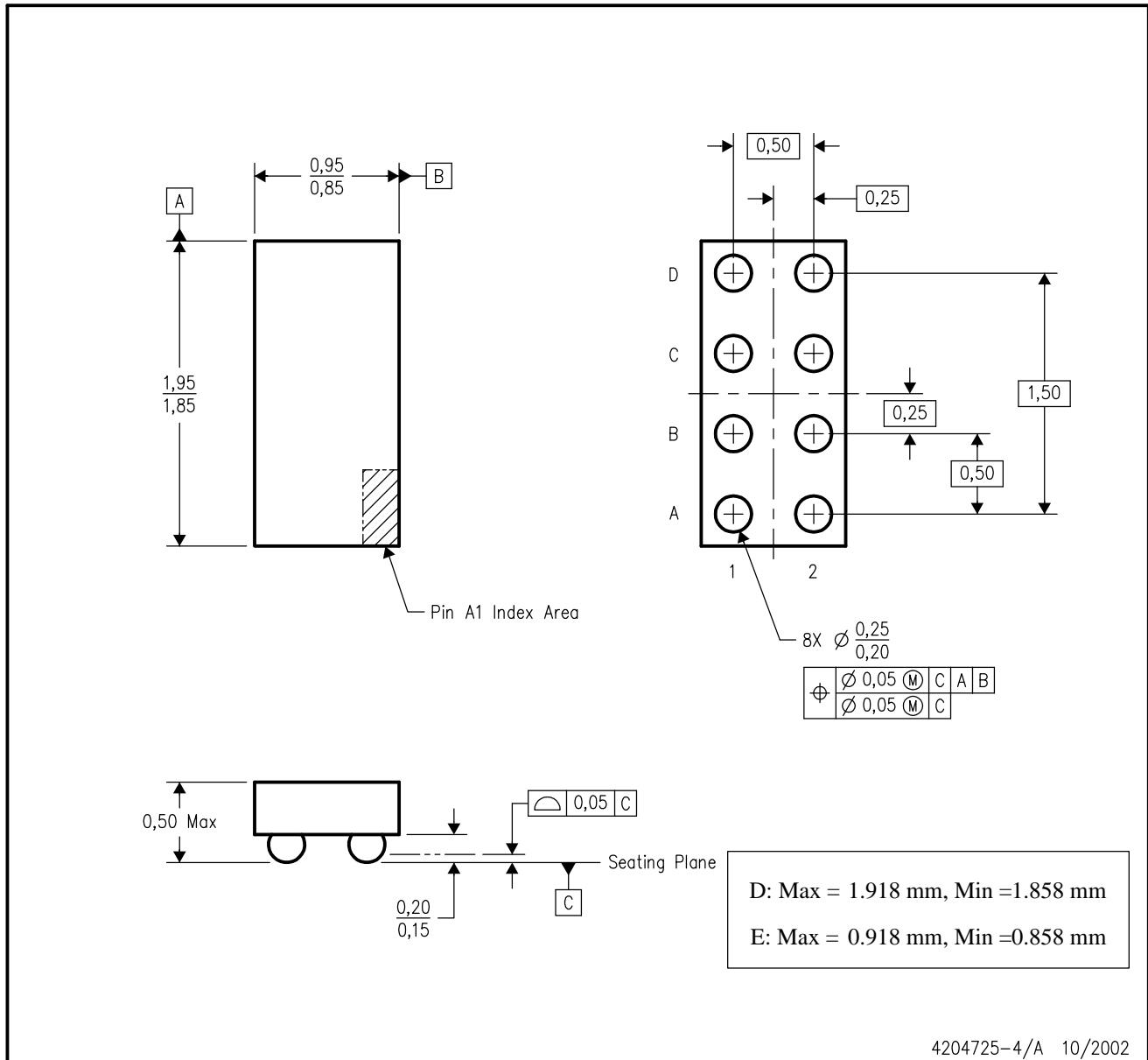


- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. NanoFree™ package configuration.

NanoFree is a trademark of Texas Instruments.

YEP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. NanoStar™ package configuration.
 - D. This package is tin-lead (SnPb). Refer to the 8 YZP package (drawing 4204741) for lead-free.

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